RoHS

HALOGEN FREE

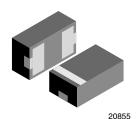
**GREEN** 



Vishay Semiconductors

# Bidirectional Symmetrical (BiSy) Single Line ESD-Protection Diode in LLP1006-2M





**MARKING** (example only)



Bar = pin 1 marking X = date code Y = type code (see table below)

#### **LINKS TO ADDITIONAL RESOURCES**





#### **FEATURES**

- Ultra compact LLP1006-2M package
- Low package height < 0.4 mm
- 1-line ESD protection
- Working range ± 3.5 V
- Low leakage current < 0.1 μA
- Low load capacitance C<sub>D</sub> = 12.5 pF
- ESD immunity acc. IEC 61000-4-2 ± 18 kV contact discharge
  - ± 20 kV air discharge
- Soldering can be checked by standard vision inspection, no X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- PATENT(S): www.vishay.com/patents
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

ORDERING INFORMATION					
DEVICE NAME ORDERING CODE		TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY		
VCUT03B1-DD1	VCUT03B1-DD1-G-08	8000	8000		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VCUT03B1-DD1	LLP1006-2M	N	0.72 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

ABSOLUTE MAXIMUM RATINGS VCUT03B1-DD1						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Acc. IEC 61000-4-5; $t_p = 8/20 \mu s$ ; single shot	I <sub>PPM</sub>	3.5	А		
Peak pulse power	Pin 1 to pin 2 Acc. IEC 61000-4-5; $t_p = 8/20 \mu s$ ; single shot	P <sub>PP</sub>	40	W		
ESD immunity	Contact discharge acc. IEC61000-4-2; 10 pulses	V	± 18	kV		
	Air discharge acc. IEC61000-4-2; 10 pulses	$V_{ESD}$	± 20			
Operating temperature	Junction temperature	TJ	-40 to +125	°C		
Storage temperature		T <sub>STG</sub>	-55 to +150	°C		

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.

## Vishay Semiconductors

#### **CUT THE SPIKES WITH VCUT03B1-DD1**

The VCUT03B1-DD1 is a bidirectional and symmetrical (BiSy) ESD protection device which clamps positive and negative overvoltage transients to ground. Connected between the signal or data line and the ground the VCUT03B1-DD1 offers a high isolation (low leakage current, low capacitance) within the specified working range. Due to the short leads and small package size of the tiny LLP1006-2M package the line inductance is very low, so that fast transients like an ESD strike can be clamped with minimal over- or undershoots.

<b>ELECTRICAL CHARACTERISTICS VCUT03B1-DD1</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines	
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	3.5	V	
Reverse voltage	At I <sub>R</sub> = 0.1 μA	$V_{R}$	3.5	-	-	V	
Reverse current	At V = 3.5 V	I <sub>R</sub>	-		0.1	μΑ	
Reverse breakdown voltage	At I =1 mA	$V_{BR}$	5.8	6.7	7.5	V	
Reverse clamping voltage	At I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	7.8	9	V	
	At I <sub>PP</sub> = I <sub>PPM</sub> = 3.5 A	V <sub>C</sub>	-	9.5	11.5	V	
Capacitance	At V = 0 V; f = 1 MHz	C <sub>D</sub>	-	12.5	15	pF	
	At V = 2.5 V; f = 1 MHz	C <sub>D</sub>	-	11.5	-	pF	

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

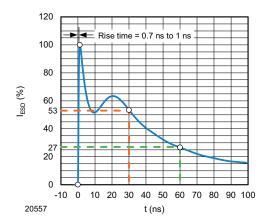


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega$ /150 pF)

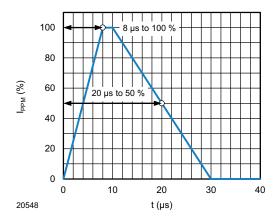


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5



# Vishay Semiconductors

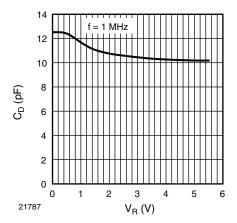


Fig. 3 - Typical Capacitance  $C_D$  vs. Reverse Voltage  $V_R$ 

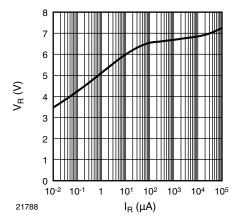


Fig. 4 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

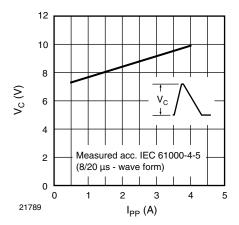


Fig. 5 - Typical Reverse Voltage  $V_{\mbox{\scriptsize R}}$  vs. Reverse Current  $I_{\mbox{\scriptsize R}}$ 

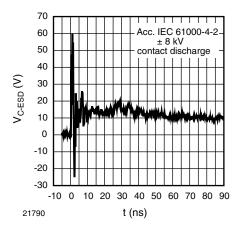


Fig. 6 - Typical Peak Clamping Voltage  $V_{\rm C}$  vs. Peak Pulse Current  $I_{\rm PP}$ 

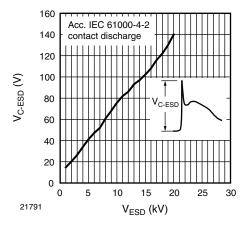
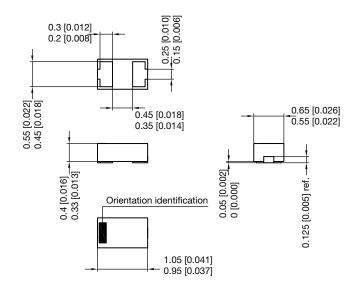


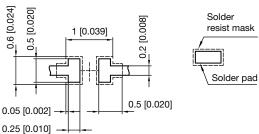
Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

# Vishay Semiconductors

### PACKAGE DIMENSIONS in millimeters (inches): LLP1006-2M



#### Foot print recommendation:

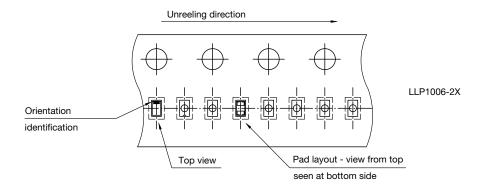


Pad Design Patented: (P)US 9.018.537 B2)

Document no.: S8-V-3906.04-005 (4)

Rev. 7 - Date: 11.May 2016

20812



S8-V-3906.04-017 (4) 02.05.2017 22965



## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.